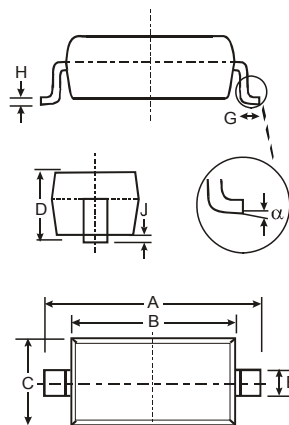


Features

- Planar Die Construction
- 500mW Power Dissipation
- General Purpose, Medium Current
- Ideally Suited for Automated Assembly Processes



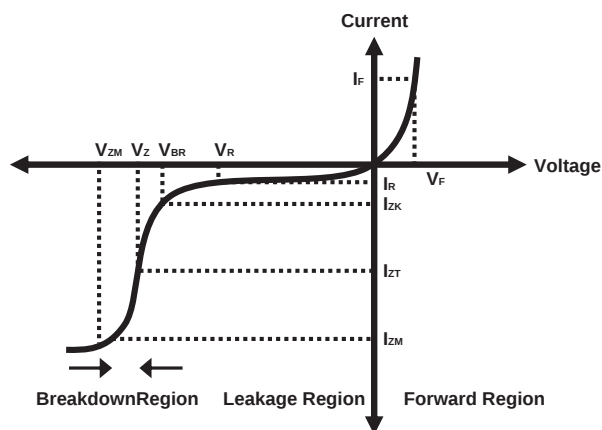
SOD-123		
Dim	Min	Max
A	3.55	3.85
B	2.55	2.85
C	1.40	1.70
D	—	1.35
E	0.45	0.65
	0.55 Typical	
G	0.25	—
H	0.11 Typical	
J	—	0.10
α	0°	8°
All Dimensions in mm		

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Value	Unit
Power Dissipation	P_{tot}	500	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{Stg}	- 65 to + 150	$^\circ\text{C}$
Thermal Resistance Junction to Ambient Air	$R_{\theta\text{JA}}$	340	$^\circ\text{C/W}$
Forward Voltage at $I_F = 10\text{ mA}$	V_F	0.9	V

- 1) Device mounted on ceramic PCB: 7.6mm x 9.4mm x 0.87mm with pad areas 25mm²
- 2) Short duration test pulse used to minimize self-heating effect
- 3) f=1KHz

Zener I vs. V Characteristics



- V_{BR} : Voltage at I_{ZK}
- I_{ZK} : Test current for voltage V_{BR}
- Z_{ZK} : Dynamic impedance at I_{ZK}
- I_{ZT} : Test current for voltage V_Z
- V_Z : Voltage at current I_{ZT}
- Z_{ZT} : Dynamic impedance at I_{ZT}
- I_{ZM} : Maximum steady state current
- V_{ZM} : Voltage at I_{ZM}



HAICHUANG SEMI

MMSZ52xxB-Series

SURFACE MOUNT ZENNER DIODE

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Device	Marking	Zener Voltage Range				Maximum Zener Impedance			Maximum Reverse Current	
		V _Z @I _{ZT}			I _{ZT}	Z _{zt} @I _{ZT}	Z _{zk} @I _{ZK}	I _{ZK}	I _R	V _R
		Nom(V)	Min(V)	Max(V)	mA	Ω		mA	μA	V
MMSZ5221B	C1	2.4	2.28	2.52	20	30	1200	0.25	100	1.0
MMSZ5223B	C3	2.7	2.57	2.84	20	30	1300	0.25	75	1.0
MMSZ5225B	C5	3.0	2.85	3.15	20	29	1600	0.25	50	1.0
MMSZ5226B	D1	3.3	3.14	3.47	20	28	1600	0.25	25	1.0
MMSZ5227B	D2	3.6	3.42	3.78	20	24	1700	0.25	15	1.0
MMSZ5228B	D3	3.9	3.71	4.10	20	23	1900	0.25	10	1.0
MMSZ5229B	D4	4.3	4.09	4.52	20	22	2000	0.25	5	1.0
MMSZ5230B	D5	4.7	4.47	4.94	20	19	1900	0.25	5	2.0
MMSZ5231B	E1	5.1	4.85	5.36	20	17	1600	0.25	5	2.0
MMSZ5232B	E2	5.6	5.32	5.88	20	11	1600	0.25	5	3.0
MMSZ5233B	E3	6.0	5.70	6.30	20	7	1600	0.25	5	3.5
MMSZ5234B	E4	6.2	5.89	6.51	20	7	1000	0.25	5	4.0
MMSZ5235B	E5	6.8	6.46	7.14	20	5	750	0.25	3	5.0
MMSZ5236B	F1	7.5	7.13	7.88	20	6	500	0.25	3	6.0
MMSZ5237B	F2	8.2	7.79	8.61	20	8	500	0.25	3	6.5
MMSZ5238B	F3	8.7	8.27	9.14	20	8	600	0.25	3	6.5
MMSZ5239B	F4	9.1	8.65	9.56	20	10	600	0.25	3	7.0
MMSZ5240B	F5	10	9.50	10.50	20	17	600	0.25	3	8.0
MMSZ5241B	H1	11	10.45	11.55	20	22	600	0.25	2	8.4
MMSZ5242B	H2	12	11.40	12.60	20	30	600	0.25	1	9.1
MMSZ5243B	H3	13	12.35	13.65	9.5	13	600	0.25	0.5	9.9
MMSZ5244B	H4	14	13.30	14.70	9.0	15	600	0.25	0.1	10
MMSZ5245B	H5	15	14.25	15.75	8.5	16	600	0.25	0.1	11
MMSZ5246B	J1	16	15.20	16.80	7.8	17	600	0.25	0.1	12
MMSZ5248B	J3	18	17.10	18.90	7.0	21	600	0.25	0.1	14
MMSZ5250B	J5	20	19.00	21.00	6.2	25	600	0.25	0.1	15
MMSZ5251B	K1	22	20.90	23.10	5.6	29	600	0.25	0.1	17
MMSZ5252B	K2	24	22.80	25.20	5.2	33	600	0.25	0.1	18
MMSZ5253B	K3	25	23.75	26.25	5.0	35	600	0.25	0.1	19
MMSZ5254B	K4	27	25.65	28.35	4.6	41	600	0.25	0.1	21
MMSZ5255B	K5	28	26.60	29.40	4.5	44	600	0.25	0.1	21
MMSZ5256B	M1	30	28.50	31.50	4.2	49	600	0.25	0.1	23
MMSZ5257B	M2	33	31.35	34.65	3.8	58	700	0.25	0.1	25
MMSZ5258B	M3	36	34.20	37.80	3.4	70	700	0.25	0.1	27
MMSZ5259B	M4	39	37.05	40.95	3.2	80	800	0.25	0.1	30
MMSZ5260B	M5	43	40.85	45.15	3.0	93	900	0.25	0.1	33
MMSZ5261B	N1	47	44.65	49.35	2.7	105	1000	0.25	0.1	36
MMSZ5262B	N2	51	48.45	53.55	2.5	125	1100	0.25	0.1	39
MMSZ5263B	N3	56	53.20	58.80	2.2	150	1300	0.25	0.1	43
MMSZ5265B	N5	62	58.90	65.10	2.0	185	1400	0.25	0.1	47
MMSZ5266B	P1	68	64.60	71.40	1.8	230	1600	0.25	0.1	52
MMSZ5267B	P2	75	71.25	78.75	1.7	270	1700	0.25	0.1	56

TYPICAL TRANSIENT CHARACTERISTICS

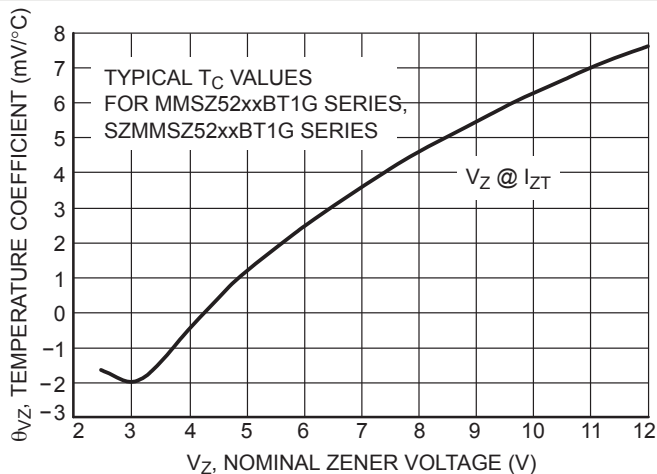


Figure 1. Temperature Coefficients
(Temperature Range -55°C to +150°C)

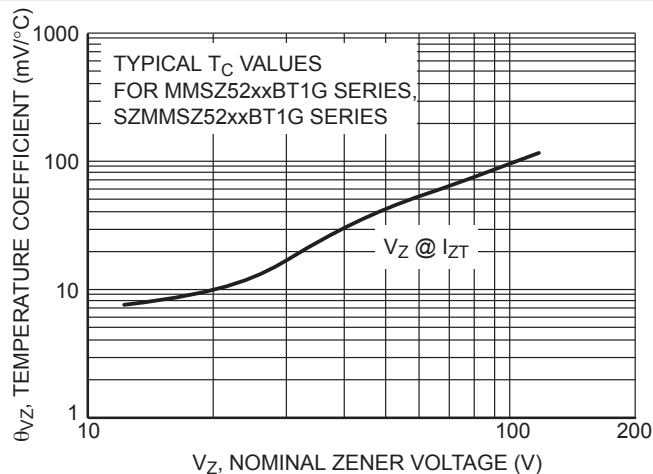


Figure 2. Temperature Coefficients
(Temperature Range -55°C to +150°C)

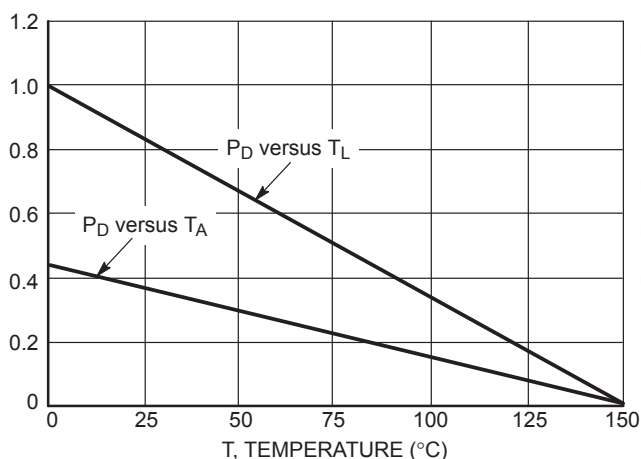


Figure 3. Steady State Power Derating

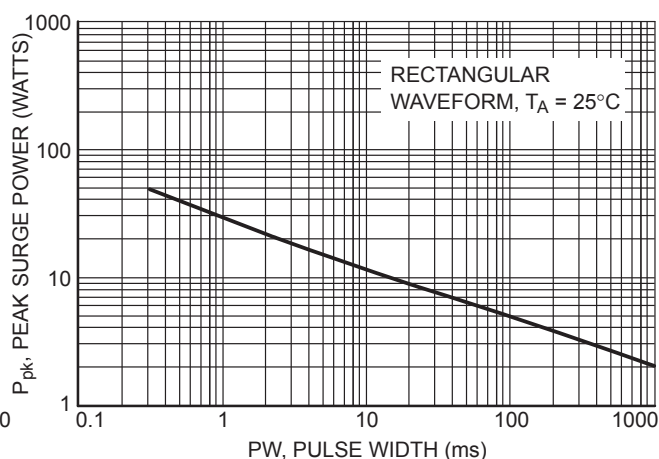


Figure 4. Maximum Nonrepetitive Surge Power

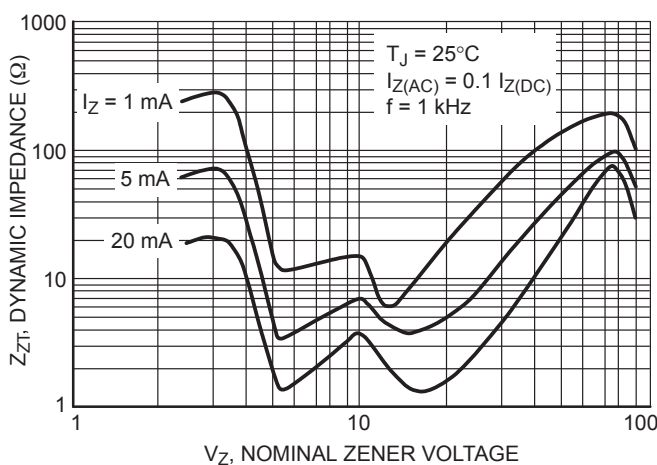


Figure 5. Effect of Zener Voltage on
Zener Impedance

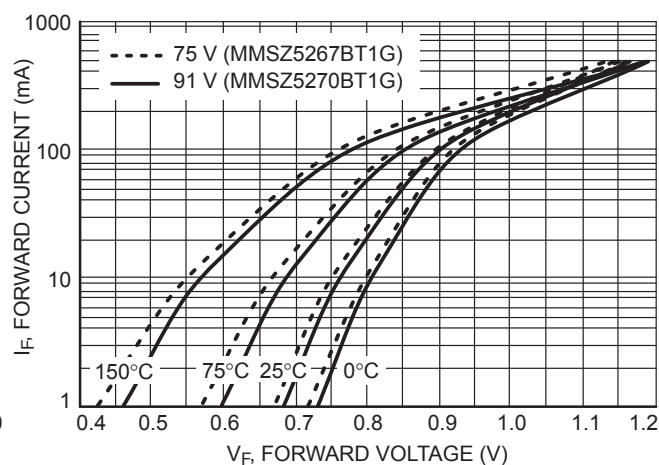


Figure 6. Typical Forward Voltage

TYPICAL TRANSIENT CHARACTERISTICS

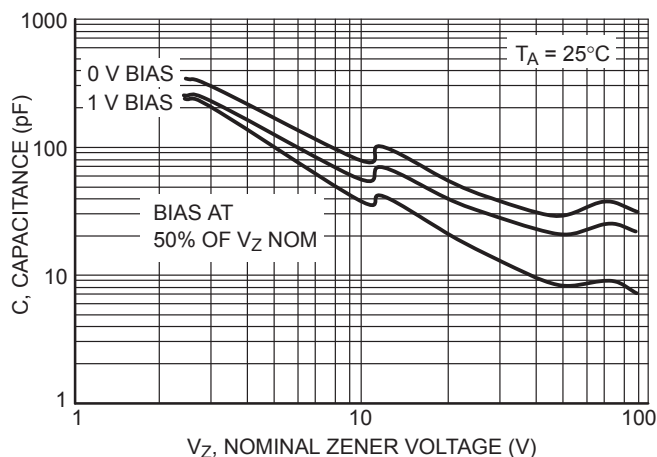


Figure 7. Typical Capacitance

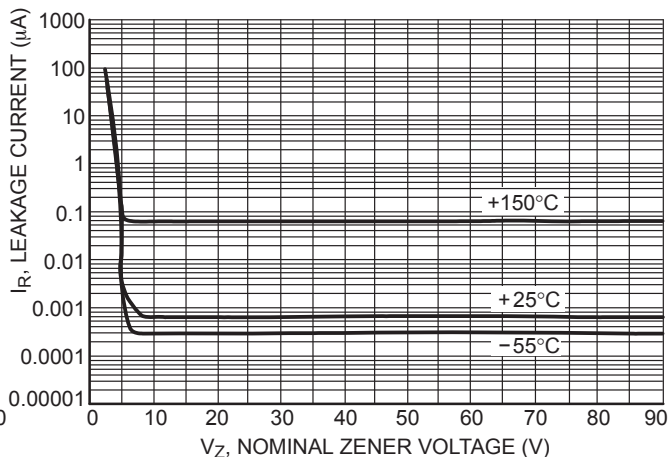


Figure 8. Typical Leakage Current

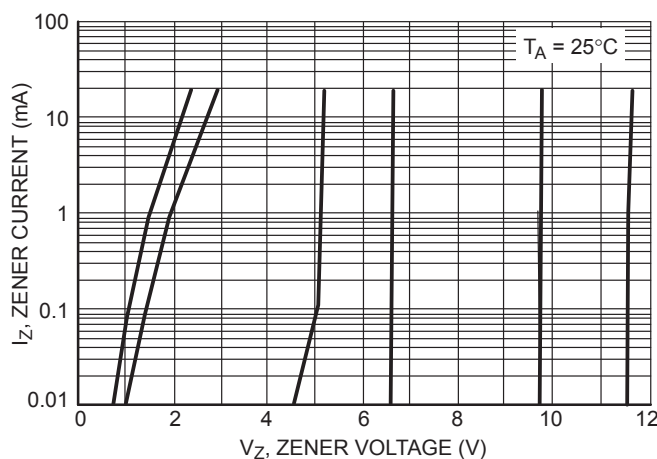


Figure 9. Zener Voltage versus Zener Current
(V_Z Up to 12 V)

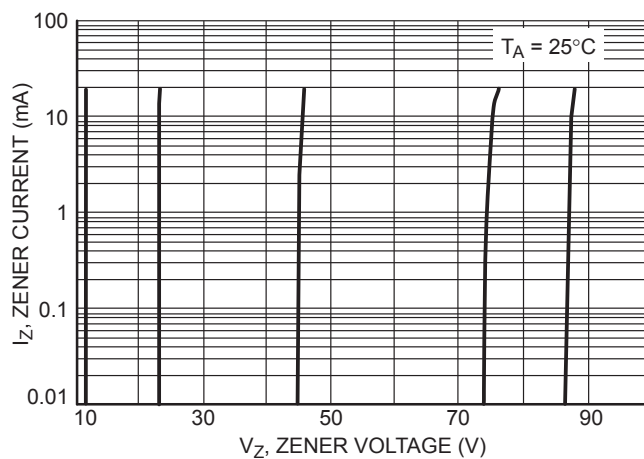


Figure 10. Zener Voltage versus Zener Current
(12 V to 91 V)

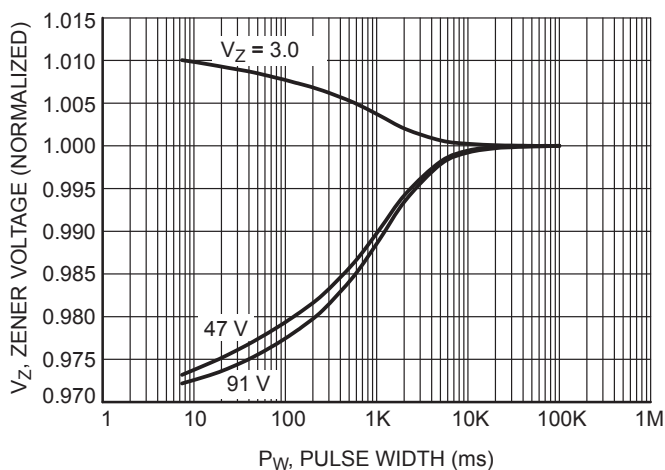


Figure 11. SOD-123 (plastic) 500 Watt Device

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